



FS84/FS85C

Fail-safe system basis chip with multiple SMPS and LDO

Rev. 7 — 7 May 2021

Product brief



1 About this document

This Product brief is intended to provide overview/summary information for the purpose of evaluating a product for design suitability. It is intended for quick reference only and should not be relied upon to contain detailed and full information.

Some of the content in this product brief is extracted from the product's full data sheet. In case of any inconsistency or conflict, the full data sheet shall prevail.

For detailed and full information, see the relevant FS84_FS85 full data sheet, available via the NXP DocStore at <https://www.docstore.nxp.com>.

2 General description

The FS85/FS84 device family is developed in compliance with ASIL D process, FS84 is ASIL B capable and FS85 is ASIL D capable. All device options are pin to pin and software compatible.

The FS85/FS84 is an automotive functionally safe multi-output power supply integrated circuit, with focus on Radar, Vision, ADAS domain controller, Radio and Infotainment applications. It includes multiple switch mode and linear voltage regulators. It offers external frequency synchronization input and output, for optimized system EMC performance.

The FS85/FS84 includes enhanced safety features, with fail-safe output, becoming a full part of a safety-oriented system partitioning, covering both ASIL B and ASIL D safety integrity level. It is developed in compliance with ISO 26262 standard and is qualified in compliance with AEC-Q100 rev H (Grade1, MSL3).

Several device versions are available, offering choice in number of output rails, output voltage setting, operating frequency and power up sequencing, to address multiple applications.

3 Features and benefits

- 60 V DC maximum input voltage for 12 V and 24 V applications
- VPRE synchronous buck controller with external MOSFETs. Configurable output voltage, switching frequency, and current capability up to 10 A peak.
- Low voltage integrated synchronous BUCK1 converter, dedicated to MCU core supply with SVS capability. Configurable output voltage and current capability up to 3.6 A peak.
- **Based on device options (see [Table 1](#)):** low voltage integrated synchronous BUCK2 converter. Configurable output voltage and current capability up to 3.6 A peak. Multi-phase capability with BUCK1 to extend the current capability up to 7.2 A peak on a single rail. Static voltage scaling capability.



- **Based on device options (see Table 1):** low voltage integrated synchronous BUCK3 converter. Configurable output voltage and current capability up to 3.6 A peak.
- BOOST converter with integrated low-side switch. Configurable output voltage and max input current up to 1.5 A peak.
- EMC optimization techniques including SMPS frequency synchronization, spread spectrum, slew rate control, manual frequency tuning
- 2x linear voltage regulators for MCU IOs and ADC supply, external physical layer. Configurable output voltage and current capability up to 400 mA DC.
- OFF mode (power down) with very low quiescent current (10 μ A typ)
- 2x input pins for wake-up detection and battery voltage sensing
- Device control via 32 bits SPI or I2C interface with CRC
- Power synchronization pin to operate 2x FS85 devices or FS85 plus an external PMIC
- Scalable portfolio from ASIL B to ASIL D with independent monitoring circuitry, dedicated interface for MCU monitoring, simple and challenger watchdog function, power good, reset and interrupt, built-in self-test, fail-safe output
- Configuration by OTP programming. Prototype enablement to support custom setting during project development in engineering mode.

4 Applications

- Radar (corner radar, imaging radar, ...)
- Vision (mono camera, stereo camera, night vision, ...)
- ADAS domain controller
- Infotainment
- V2x

5 Ordering information

Table 1. Device options

| Device options | BUCK1 | BUCK2 | BUCK3 | FCCU | VMONx | ASIL |
|----------------|-------|-------|-------|----------|---------|------|
| FS8400 | Yes | No | No | No | up to 2 | B |
| FS8405 | Yes | No | No | optional | up to 4 | B |
| FS8410 | Yes | No | Yes | No | up to 2 | B |
| FS8415 | Yes | No | Yes | optional | up to 4 | B |
| FS8420 | Yes | Yes | No | No | up to 2 | B |
| FS8425 | Yes | Yes | No | optional | up to 4 | B |
| FS8430 | Yes | Yes | Yes | No | up to 2 | B |
| FS8435 | Yes | Yes | Yes | optional | up to 4 | B |
| FS8500 | Yes | No | No | Yes | up to 4 | D |
| FS8510 | Yes | No | Yes | Yes | up to 4 | D |
| FS8520 | Yes | Yes | No | Yes | up to 4 | D |
| FS8530 | Yes | Yes | Yes | Yes | up to 4 | D |

Table 2. Ordering information

| Part number ^[1] ^{[2][3]} | Application target | Package | | |
|--|---|---------|---|-----------|
| | | Name | Description | Version |
| MC33FS8400G0ES MC33FS8400G0KS | Superset covering FS8400 configurations | HVQFN56 | plastic thermal enhanced very thin quad flat package; no leads; wettable flank, 56 terminals; 0.5 mm pitch, 8 mm x 8 mm x 0.85 mm body See Section 13.1 "Package outline" for differences. | SOT684-23 |
| MC33FS8400G5ES MC33FS8400G5KS | Camera | | | |
| MC33FS8405G0ES MC33FS8405G0KS | Superset covering FS8405 configurations | | | |
| MC33FS8410G0ES MC33FS8410G0KS | Superset covering FS8410 configurations | | | |
| MC33FS8410G3ES MC33FS8410G3KS | Radar with NXP S32R274 MCU | | | |
| MC33FS8410G6ES MC33FS8410G6KS | Gateway with NXP MPC5748G MCU | | | |
| MC33FS8415G0ES MC33FS8415G0KS | Superset covering FS8415 configurations | | | |
| MC33FS8415GJES MC33FS8415GJKS | For Radar with NXP S32R294 + TEF810x for 12 V/24 V application ^[4] | | | |
| MC33FS8415GYES MC33FS8415GYKS | For Radar with NXP S32R294 + TEF810x/TEF82xx for 12 V/24 V application | | | |
| MC33FS8420G0ES MC33FS8420G0KS | Superset covering FS8420 configurations | | | |
| MC33FS8425G0ES MC33FS8425G0KS | Superset covering FS8425 configurations | | | |
| MC33FS8430G0ES MC33FS8430G0KS | Superset covering FS8430 configurations | | | |
| MC33FS8430G1ES MC33FS8430G1KS | Camera with NXP S32V MCU and PF8x PMIC | | | |
| MC33FS8430G2ES MC33FS8430G2KS | Camera with NXP S32V MCU | | | |
| MC33FS8430G4ES MC33FS8430G4KS | Camera | | | |
| MC33FS8435G0ES MC33FS8435G0KS | Superset covering FS8435 configurations | | | |
| MC33FS8500A0ES MC33FS8500A0KS | Superset covering FS8500 configurations | | | |
| MC33FS8510A0ES MC33FS8510A0KS | Superset covering FS8510 configurations | | | |
| MC33FS8510A2ES MC33FS8510A2KS | Domain controller | | | |
| MC33FS8510D3ES MC33FS8510D3KS | Battery monitoring system | | | |
| MC33FS8520A0ES MC33FS8520A0KS | Superset covering FS8520 configurations | | | |
| MC33FS8530A0ES MC33FS8530A0KS | Superset covering FS8530 configurations | | | |
| MC33FS8530A1ES MC33FS8530A1KS | Camera | | | |
| MC33FS8530A4ES MC33FS8530A4KS | Imaging radar with NXP S32R MCU | | | |

[1] To order parts in tape and reel, add the R2 suffix to the part number.

[2] Step-cut wettable flank for part numbers ending in ES

Dimple wettable flank for part numbers ending in KS

- [3] The part numbers with KS suffix are recommended for new designs.
- [4] FS8415GY part is recommended for new designs

A0 and G0 parts are non-programmed OTP configurations. Pre-programmed OTP configurations (other than BUCK regulators and ASIL level) are managed through part number extension: A1 to FZ for FS85 and G1 to LZ for FS84.

For a custom OTP configuration, contact your local NXP sales representative.

6 Simplified application diagram

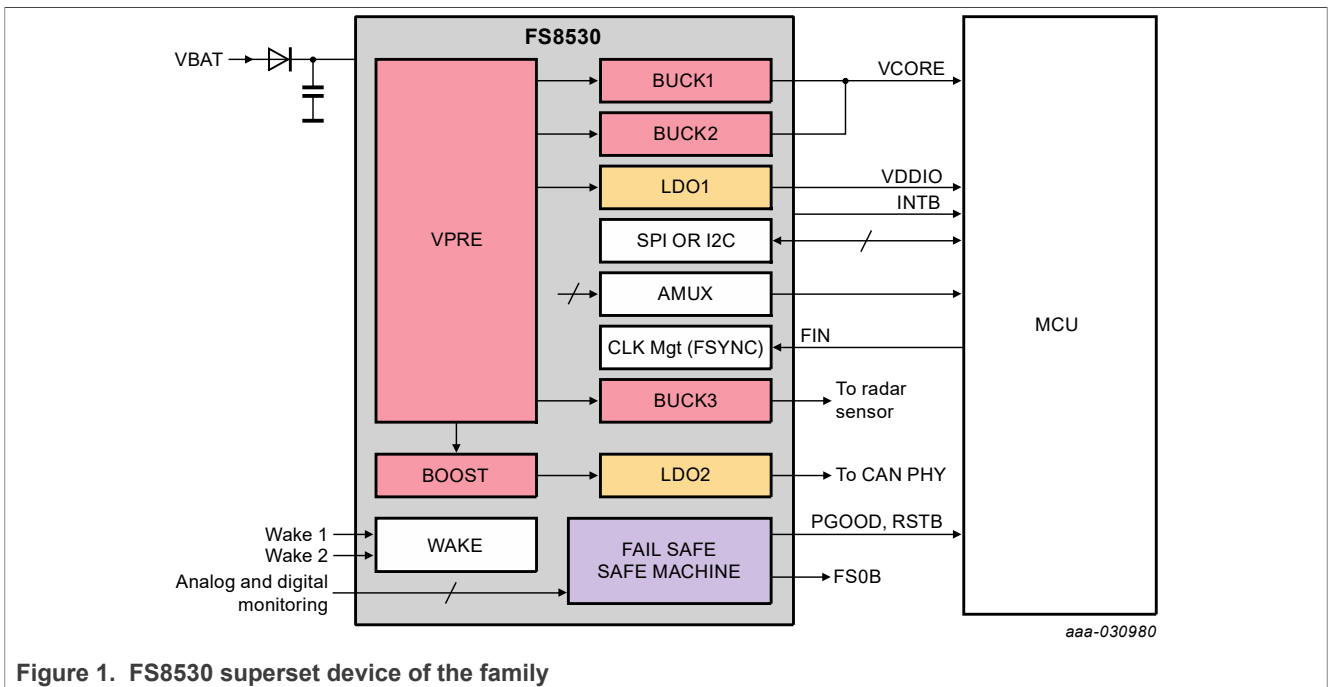


Figure 1. FS8530 superset device of the family

7 Pinning information

7.1 Pinning

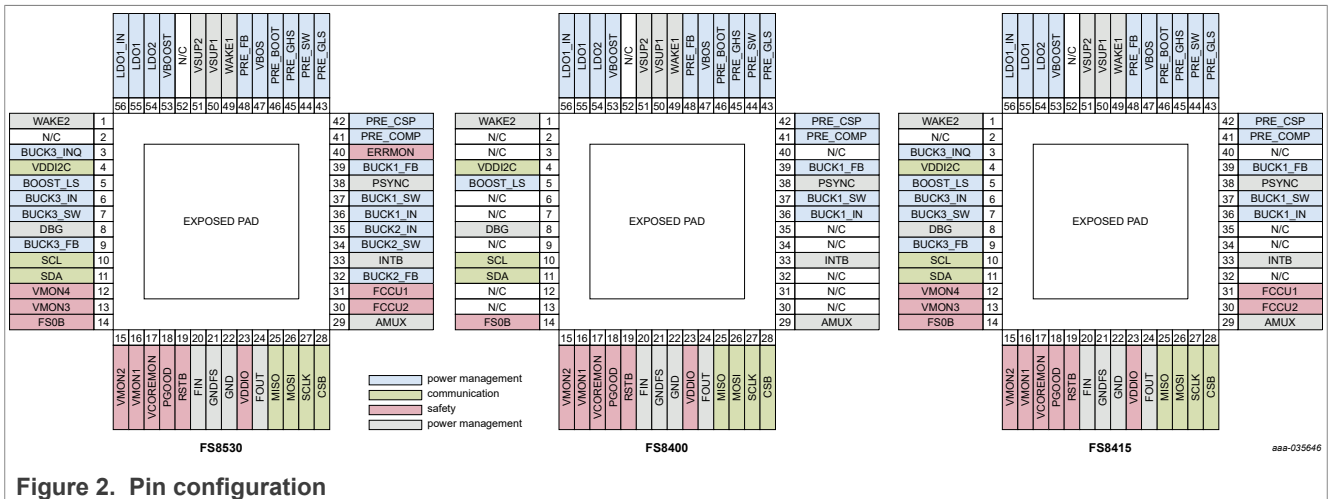


Figure 2. Pin configuration

7.2 Pin description

Table 3. Pin description

| Symbol | Pin | Type | Description ^[1] |
|-----------|-----|-------------|---|
| WAKE2 | 1 | A_IN / D_IN | Wake-up input 2 An external serial resistor is required if WAKE2 is a global pin |
| N/C | 2 | N/C | Not connected pin |
| BUCK3_INQ | 3 | A_IN | Low voltage Buck3 quiet input voltage |
| VDDI2C | 4 | A_IN | Input voltage for I2C buffers |
| BOOST_LS | 5 | A_IN | Boost low-side drain of internal MOSFET |
| BUCK3_IN | 6 | A_IN | Low voltage Buck3 input voltage |
| BUCK3_SW | 7 | A_OUT | Low voltage Buck3 switching node |
| DBG | 8 | A_IN | Debug mode entry |
| BUCK3_FB | 9 | A_IN | Low voltage Buck3 voltage feedback |
| SCL | 10 | D_IN | I2C bus Clock input |
| SDA | 11 | D_IN/OUT | I2C bus Bidirectional data line |
| VMON4 | 12 | A_IN | Voltage monitoring input 4 |
| VMON3 | 13 | A_IN | Voltage monitoring input 3 |
| FS0B | 14 | D_OUT | Fail-safe output 0 Active low Open drain structure |
| VMON2 | 15 | A_IN | Voltage monitoring input 2 |
| VMON1 | 16 | A_IN | Voltage monitoring input 1 |
| VCOREMON | 17 | A_IN | VCORE monitoring input: Must be connected to Buck1 output voltage |
| PGOOD | 18 | D_OUT | Power good output Active low Pull up to VDDIO mandatory |
| RSTB | 19 | D_OUT | Reset output Active low The main function is to reset the MCU. Reset input voltage is monitored to detect external reset and fault condition. Pull up to VDDIO mandatory |
| FIN | 20 | D_IN | Frequency synchronization input |
| GND FS | 21 | GND | Fail-safe ground |
| GND | 22 | GND | Main ground |
| VDDIO | 23 | A_IN | Input voltage for SPI, FOUT and AMUX buffers Allow voltage compatibility with MCU I/Os |
| FOUT | 24 | D_OUT | Frequency synchronization output |
| MISO | 25 | D_OUT | SPI bus Master input slave output |
| MOSI | 26 | D_IN | SPI bus Master output slave Input |
| SCLK | 27 | D_IN | SPI bus Clock input |
| CSB | 28 | D_IN | Chip select (active low) |

Table 3. Pin description...continued

| Symbol | Pin | Type | Description ^[1] |
|----------|-----|-------------|---|
| AMUX | 29 | A_OUT | Multiplexed output to connect to MCU ADC Selection of the analog parameter through SPI or I2C |
| FCCU2 | 30 | D_IN | MCU error monitoring input 2 |
| FCCU1 | 31 | D_IN | MCU error monitoring input 1 |
| BUCK2_FB | 32 | A_IN | Low voltage Buck2 voltage feedback |
| INTB | 33 | D_OUT | Interrupt output |
| BUCK2_SW | 34 | A_OUT | Low voltage Buck2 switching node |
| BUCK2_IN | 35 | A_IN | Low voltage Buck2 input voltage |
| BUCK1_IN | 36 | A_IN | Low voltage Buck1 input voltage |
| BUCK1_SW | 37 | A_OUT | Low voltage Buck1 switching node |
| PSYNC | 38 | D_IN/OUT | Power synchronization input/output |
| BUCK1_FB | 39 | A_IN | Low voltage Buck1 voltage feedback |
| ERRMON | 40 | D_IN | External IC error monitoring input |
| PRE_COMP | 41 | A_IN | VPRE compensation network |
| PRE_CSP | 42 | A_IN | VPRE positive current sense input |
| PRE_GLS | 43 | A_OUT | VPRE low-side gate driver for external MOSFET |
| PRE_SW | 44 | A_IN | VPRE switching node |
| PRE_GHS | 45 | A_OUT | VPRE high-side gate driver for external MOSFET |
| PRE_BOOT | 46 | A_IN/OUT | VPRE bootstrap capacitor |
| VBOS | 47 | A_OUT | Best of supply output voltage |
| PRE_FB | 48 | A_IN | VPRE voltage feedback and negative current sense input |
| WAKE1 | 49 | A_IN / D_IN | Wake up input 1 An external serial resistor is required if WAKE1 is a global pin |
| VSUP1 | 50 | A_IN | Power supply 1 of the device An external reverse battery protection diode in series is mandatory |
| VSUP2 | 51 | A_IN | Power supply 2 of the device An external reverse battery protection diode in series is mandatory |
| N/C | 52 | N/C | Not connected pin |
| VBOOST | 53 | A_IN | VBOOST voltage feedback |
| LDO2 | 54 | A_OUT | Linear regulator 2 output voltage |
| LDO1 | 55 | A_OUT | Linear regulator 1 output voltage |
| LDO1_IN | 56 | A_IN | Linear regulator 1 input voltage |
| EP | 57 | GND | Expose pad (BUCK1, BUCK2 and BUCK3 low-side GNDs are connected to the expose pad) Must be connected to GND |

[1] See [Connection of unused pins](#) for connection of unused pins.

8 Maximum ratings

Table 4. Maximum ratings

All voltages are with respect to ground, unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|-------------------------------|--|------|------|------|
| Voltage ratings | | | | | |
| VSUP1/2 | DC voltage | power supply VSUP1,2 pins | -0.3 | 60 | V |
| WAKE1/2 | DC voltage | WAKE1,2 pins; external serial resistor mandatory | -1.0 | 60 | V |
| PRE_SW | DC voltage | PRE_SW pin | -2.0 | 60 | V |
| | Transient voltage < 20 ns | | -3.0 | 60 | V |
| VMONx, FS0B | DC voltage | VMON1,2,3,4, VCOREMON, FS0B pins | -0.3 | 60 | V |
| PRE_GHS, PRE_BOOT | DC voltage | PRE_GHS, PRE_BOOT pins | -0.3 | 65.5 | V |
| DBG | DC voltage | DBG pin | -0.3 | 10 | V |
| BOOST_LS | DC voltage | BOOST_LS pin | -0.3 | 8.5 | V |
| VBOOST, LDO1_IN | DC voltage | VBOOST, LDO1_IN pins | -0.3 | 6.5 | V |
| BUCKx_IN | DC voltage | BUCK1_IN, BUCK2_IN, BUCK3_IN, BUCK3_INQ | -1.0 | 5.5 | V |
| BUCKx_IN | Transient voltage < 3 μ s | BUCK1_IN, BUCK2_IN, BUCK3_IN, BUCK3_INQ | -1.0 | 6.5 | V |
| BUCKx_SW | Transient voltage < 20 ns | BUCK1_SW, BUCK2_SW, BUCK3_SW | -3.0 | 6.5 | V |
| All other pins | DC voltage | at all other pins | -0.3 | 5.5 | V |
| Current ratings | | | | | |
| I_WAKE | Maximum current capability | WAKE1,2 | -5.0 | 5.0 | mA |
| I_SUP | Maximum current capability | VSUP1,2 | -5.0 | — | mA |

9 Electrostatic discharge

9.1 Human body model (JESD22/A114)

The device is protected up to ± 2 kV, according to the human body model at 100 pF and 1.5 k Ω . This protection is ensured at all pins.

9.2 Charged device model

The device is protected up to ± 500 V, according to the AEC Q100 - 011 charged device model standard. This protection is ensured at all pins.

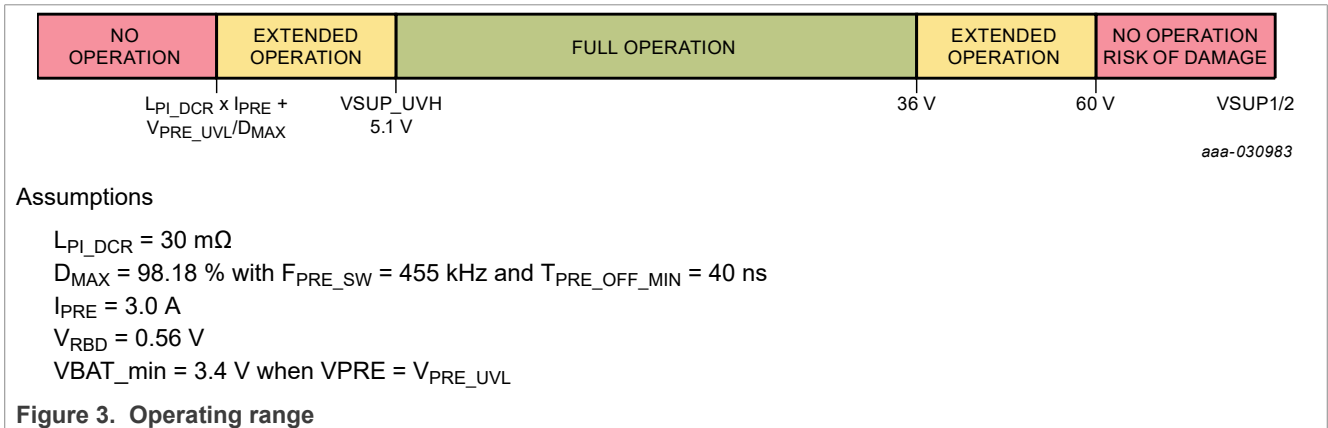
9.3 Discharged contact test

The device is protected up to ± 8 kV, according to the following discharged contact tests.

- Discharged contact test (IEC61000-4-2) at 150 pF and 330 Ω
- Discharged contact test (ISO10605.2008) at 150 pF and 2 k Ω
- Discharged contact test (ISO10605.2008) at 330 pF and 2 k Ω

This protection is ensured at VSUP1, VSUP2, WAKE1, WAKE2, FS0B pins.

10 Operating range



- Below VSUP_UVH threshold, the extended operation range depends on VPRE output voltage configuration and external components.
 - When VPRE is configured at 5.0 V, VPRE may not remain in its regulation range.
 - VSUP minimum voltage depends on external components (L_{PI_DCR}) and application conditions (I_{PRE} , F_{PRE_SW}).
- When VPRE is switching at 455 kHz, the FS85/FS84 maximum continuous operating voltage is 36 V. It has been validated at 48 V for limited duration of 15 minutes at room temperature to satisfy the jump start requirement of 24 V applications. It can sustain 58 V load dump without external protection.
- When VPRE is switching at 2.2 MHz, the FS85/FS84 maximum continuous operating voltage is 18 V. It will be validated at 26 V for limited duration of 2 minutes at room temperature to satisfy the jump start requirement of 12 V applications and 35 V load dump.

11 Thermal ratings

Table 5. Thermal ratings

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|--|--|-----|-----|------|
| R _{θJA} | Thermal resistance junction to ambient | 2s2p circuit board ^[1] | — | 31 | °C/W |
| R _{θJA} | Thermal resistance junction to ambient | 2s6p circuit board ^[1] | — | 23 | °C/W |
| R _{θJB} | Thermal resistance junction to board | 2s2p circuit board ^[1] | — | 15 | °C/W |
| R _{θJB} | Thermal resistance junction to board | 2s6p circuit board ^[1] | — | 10 | °C/W |
| R _{θJC_BOT} | Thermal resistance junction to case bottom | between the die and the solder pad on the bottom of the package ^[1] | — | 1 | °C/W |
| R _{θJP_TOP} | Thermal resistance junction to package top | between package top and the junction temperature ^[1] | — | 3 | °C/W |
| T _A | Ambient temperature (Grade 1) | | -40 | 125 | °C |
| T _J | Junction temperature (Grade 1) | | -40 | 150 | °C |
| T _{STG} | Storage temperature | | -55 | 150 | °C |

[1] per JEDEC JESD51-2 and JESD51-8

12 Characteristics

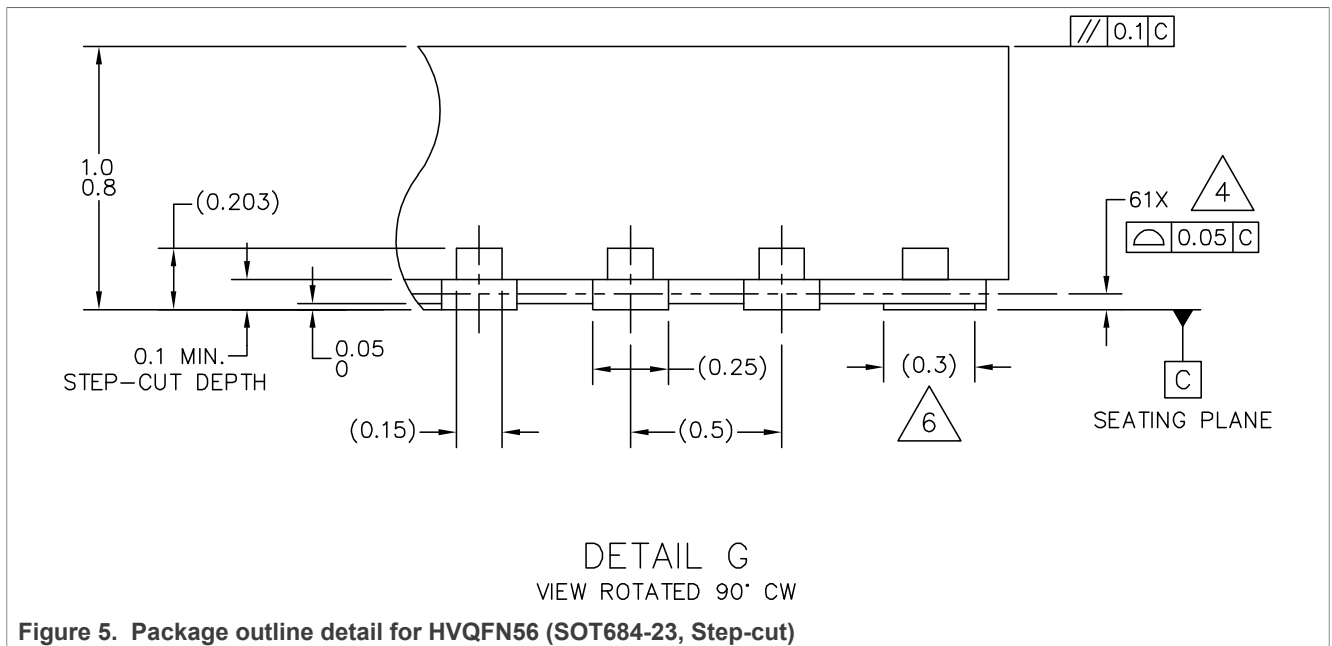
Table 6. Electrical characteristics

$T_A = -40\text{ °C}$ to 125 °C , unless otherwise specified. $VSUP = VSUP_UVH$ to 36 V, unless otherwise specified. All voltages referenced to ground.

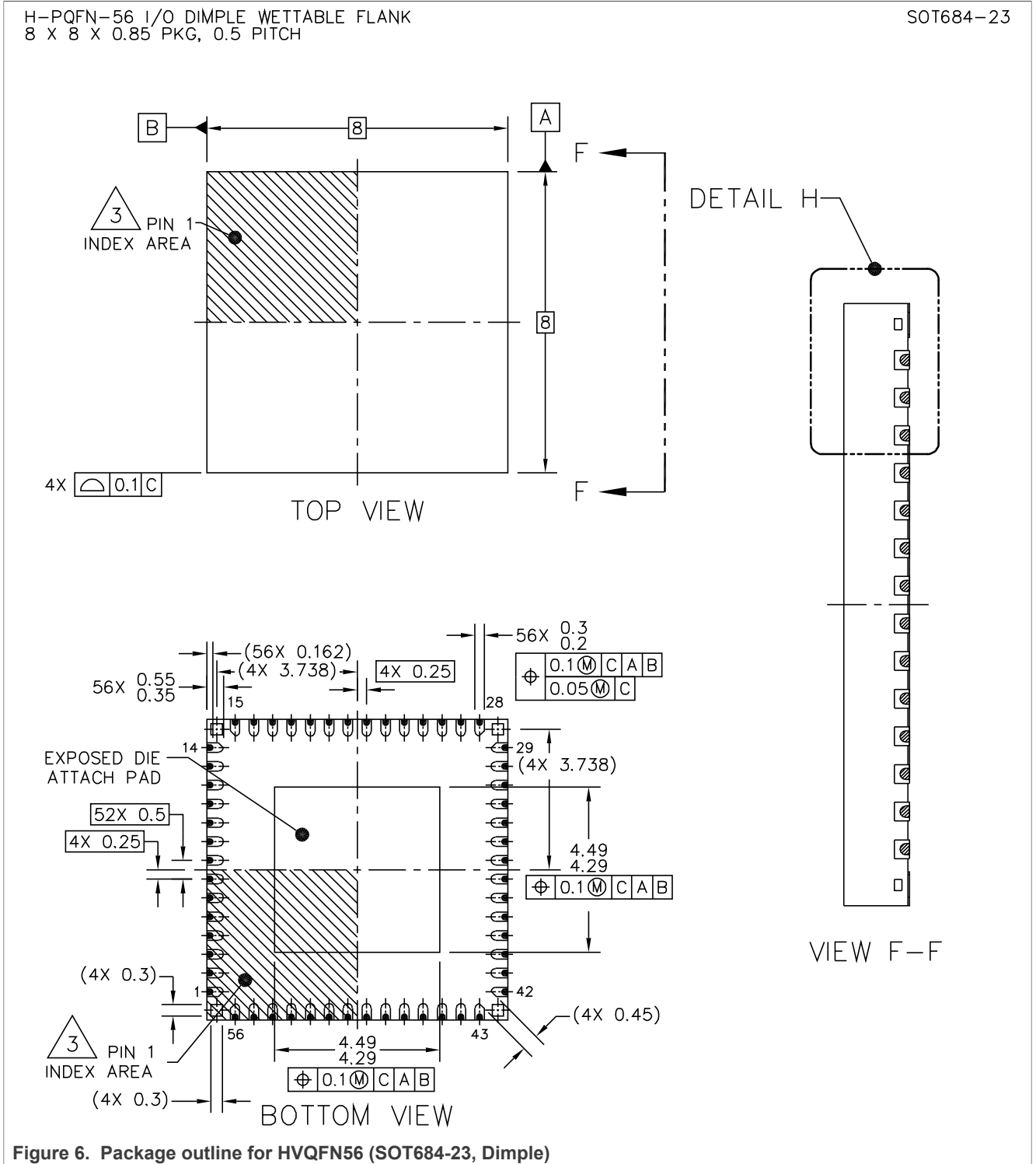
| Symbol | Parameter | Min | Typ | Max | Unit |
|--------------------|--|-----|-----|-----|---------------|
| Power supply | | | | | |
| I_{SUP_NORMAL} | Current in Normal mode, all regulators ON ($I_{OUT} = 0$) | — | 15 | 25 | mA |
| $I_{SUP_STANDBY}$ | Current in Standby mode, all regulators OFF except VBOS | — | 5 | 10 | mA |
| I_{SUP_OFF1} | Current in OFF mode (Power Down), $T_A < 85\text{ °C}$ | — | 10 | 15 | μA |
| I_{SUP_OFF2} | Current in OFF mode (Power Down), $T_A = 125\text{ °C}$ | — | — | 25 | μA |
| V_{SUP_UV7} | $VSUP$ undervoltage threshold (7.0 V) | 7.2 | 7.5 | 7.8 | V |
| V_{SUP_UVH} | $VSUP$ undervoltage threshold high (during power up and V_{sup} rising) OTP_VSUP_CFG = 0 | 4.7 | — | 5.1 | V |
| | $VSUP$ undervoltage threshold high (during power up and V_{sup} rising) OTP_VSUP_CFG = 1 | 6.0 | — | 6.4 | V |
| V_{SUP_UVL} | $VSUP$ undervoltage threshold low (during power up and V_{sup} falling) OTP_VSUP_CFG = 0 | 4.0 | — | 4.4 | V |
| | $VSUP$ undervoltage threshold low (during power up and V_{sup} falling) OTP_VSUP_CFG = 1 | 5.3 | — | 5.7 | V |
| T_{SUP_UV} | V_{SUP_UV7} , V_{SUP_UVH} and V_{SUP_UVL} filtering time | 6.0 | 10 | 15 | μs |

13 Package information

FS85/FS84 package is a QFN (sawn), thermally enhanced wettable flanks, 8 x 8 x 0.85 mm, 0.5 mm pitch, 56 pins.

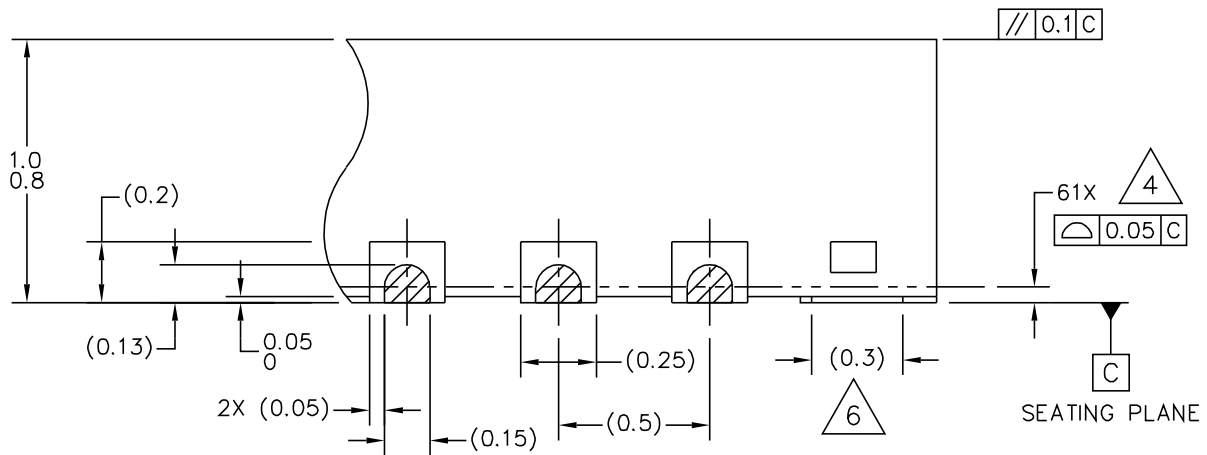


13.1.2 Dimple wettable flank



H-PQFN-56 I/O DIMPLE WETTABLE FLANK
8 X 8 X 0.85 PKG, 0.5 PITCH

SOT684-23



DETAIL H
VIEW ROTATED 90° CW

Figure 7. Package outline detail for HVQFN56 (SOT684-23, Dimple)

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PIN 1 FEATURE SHAPE, SIZE AND LOCATION MAY VARY.
4. COPLANARITY APPLIES TO LEADS, DIE ATTACH FLAG AND CORNER NON-FUNCTIONAL PADS.
5. MIN. METAL GAP SHOULD BE 0.25 MM.
6. ANCHORING PADS.

Figure 8. Package outline notes for HVQFN56 (SOT684-23)

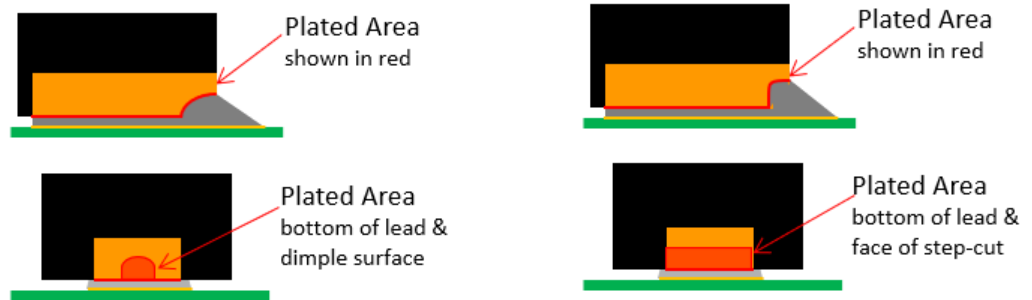
13.1.3 Package comparison

Table 7. Package comparison

| Item | Dimple wettable flank | Step-cut wettable flank |
|----------------------|-----------------------|-------------------------|
| Package size (x,y,z) | 8x8x0.85 mm3 | 8x8x0.85 mm3 |

Table 7. Package comparison...continued

| Item | Dimple wettable flank | Step-cut wettable flank |
|-----------------|-----------------------|-------------------------|
| Package | QFN56 8*8 | QFN56 8*8 |
| Epoxy | EN4900G* | EN4900G* |
| Wire | AuPdCu Wire 1.3mil | AuPdCu Wire 1.3mil |
| Compound | CEL-9240HF10AN4 | G700LA fine catalyst |
| Lead frame | PPF+RT | SN Plated |
| Wettable flank | Dimple solution | Step Cut |
| Part number | MC33FS85XXXXKS | MC33FS85XXXXES |
| MSL / Reflow °C | 3 / 260 | 3 / 260 |



13.2 Landing pad information

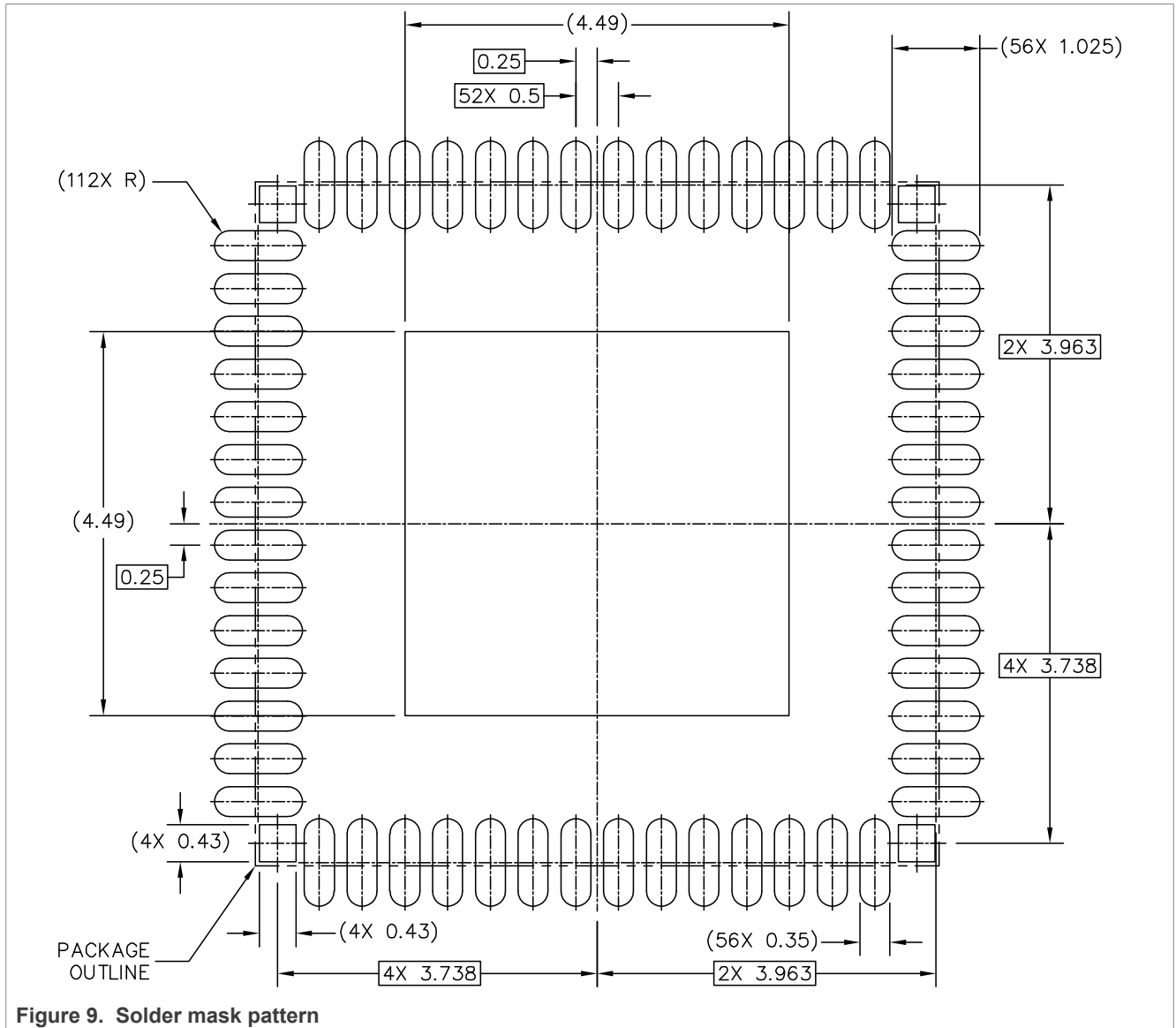
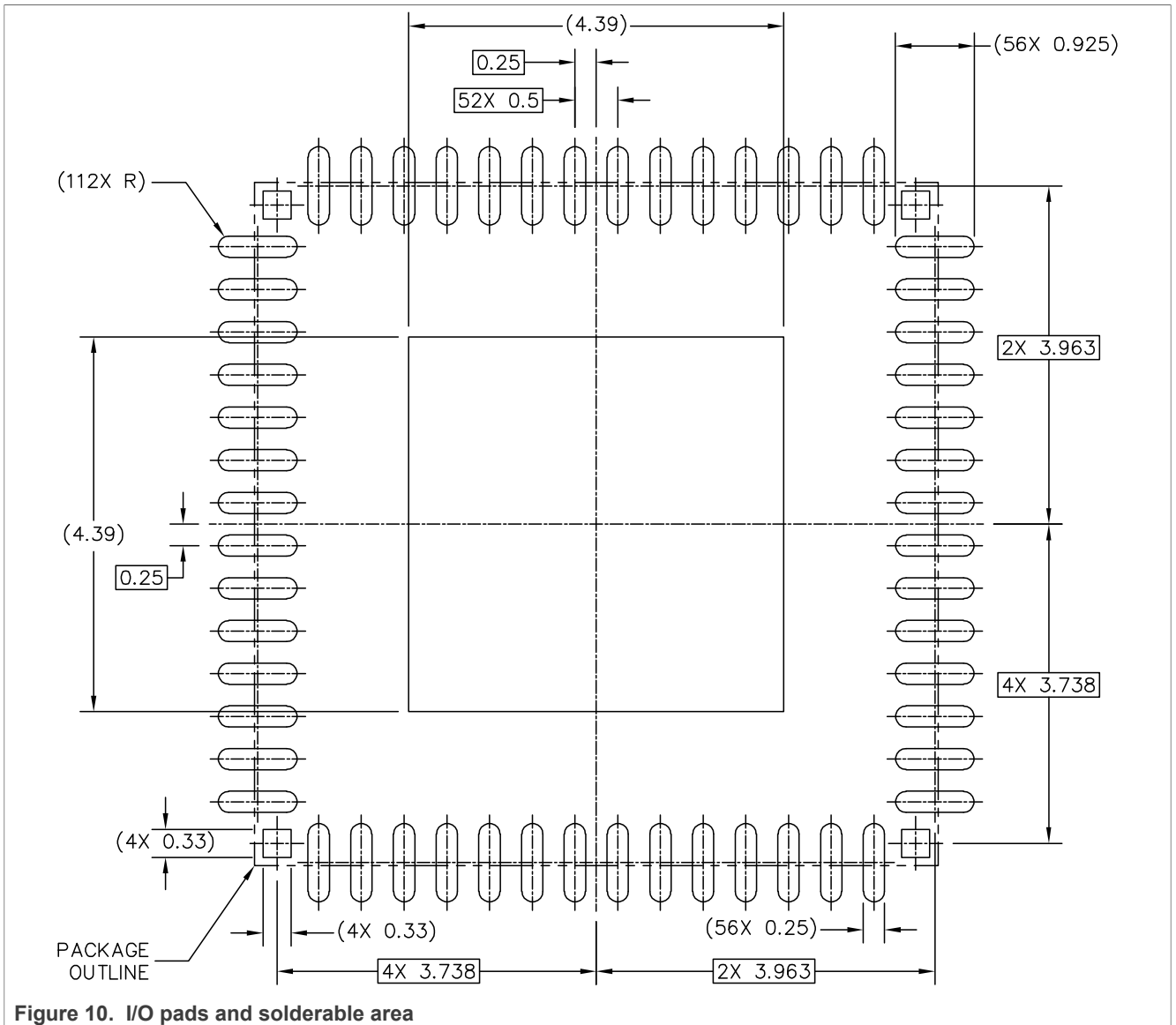


Figure 9. Solder mask pattern



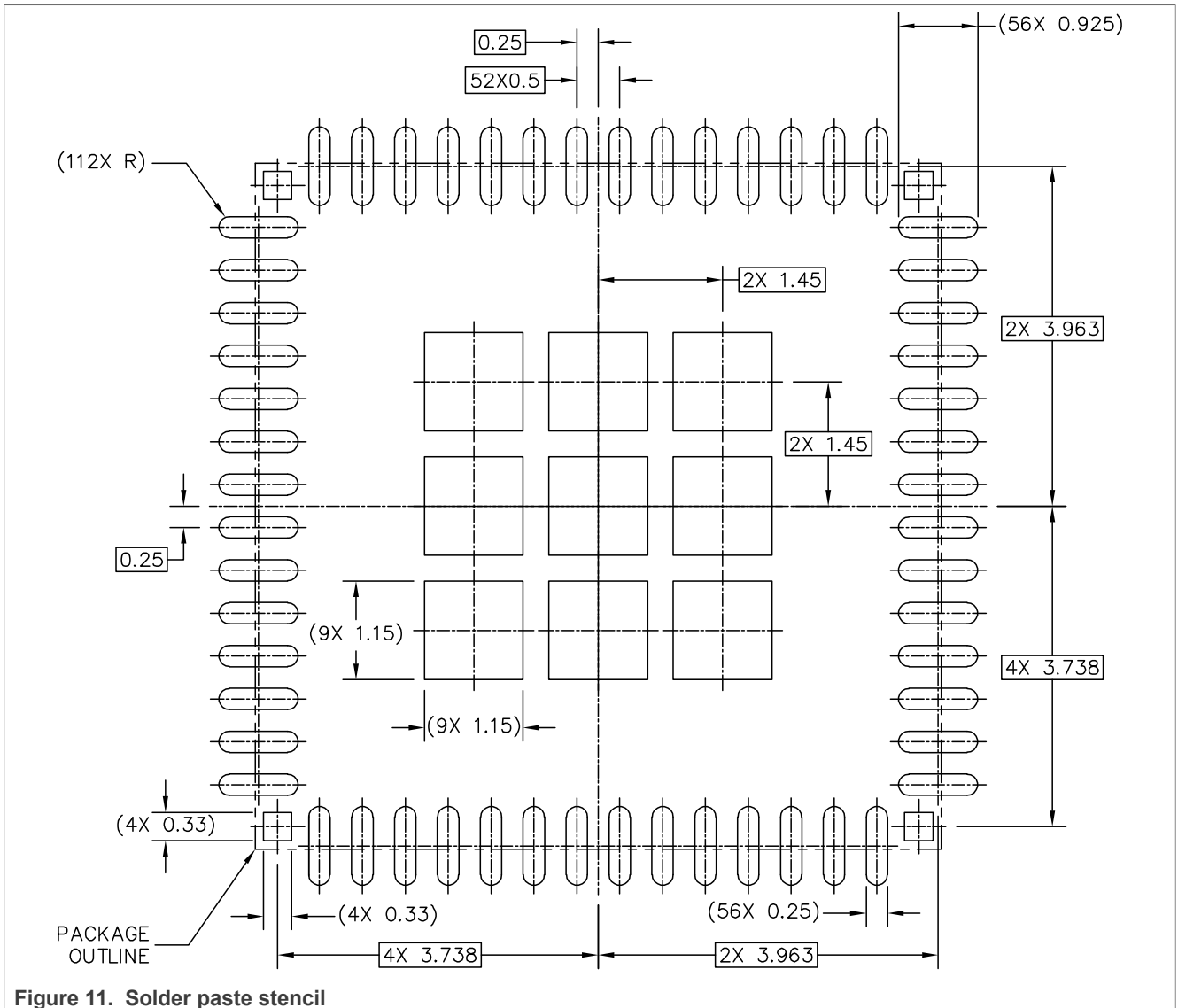


Figure 11. Solder paste stencil

14 References

- [1] **FS8400** — Safety System Basis Chip for S32 Microcontrollers, fit for ASIL B
<http://www.nxp.com/FS8400>
- [2] **FS8500** — Safety System Basis Chip for S32 Microcontroller, fit for ASIL D
<http://www.nxp.com/FS8500>
- [3] **FS85_PDTCALC** — VPRES compensation network calculation and power dissipation tool (Excel file)
<https://www.nxp.com/downloads/en/calculators/FS85-PDTCALC.xlsx>
- [4] **FS85_FMEDA** — FMEDA analysis ^[1]
- [5] **FS85_VPRE_Simplis_Model** Simplis model for stability and transient simulations ^[1]
- [6] **KITFS85FRDMEVM** — detailed information on this board, including documentation, downloads, and software and tools
<http://www.nxp.com/KITFS85FRDMEVM>

- [7] **KITFS85SKTEVM** — detailed information on this board, including documentation, downloads, and software and tools
<http://www.nxp.com/KITFS85SKTEVM>
- [8] **KITFS85AEEVM** — detailed information on this board, including documentation, downloads, and software and tools
<http://www.nxp.com/KITFS85AEEVM>
- [9] **AN12333** — FS84, FS85 product guidelines application note
https://www.nxp.com/webapp/sps/download/mod_download.jsp?colCode=AN12333
- [10] **FS85_FS84_OTP_Config.xlsm** — OTP configuration file
<https://www.nxp.com/webapp/Download?colCode=FS85-FS84-OTP>
- [11] **FS85_FS84SMUG** — Safety manual ^[1]
- [12] **ES_FS84_FS85** — Errata sheet
<https://www.nxp.com/webapp/Download?colCode=ES-FS84-FS85>

[1] Contact NXP sales representative.

15 Legal information

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